

DF3A6.8FUT1

Preferred Device

Zener Transient Voltage Suppressor

Dual Common Anode Zeners for ESD Protection

These dual monolithic silicon zener diodes are designed for applications requiring transient overvoltage protection capability. They are intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems, medical equipment and other applications. Their dual junction common anode design protects two separate lines using only one package. These devices are ideal for situations where board space is at a premium.

Features

- Pb-Free Package is Available
- SC-70 Package Allows Two Separate Unidirectional Configurations
- Low Leakage < 1.0 μ A @ 5.0 V
- Breakdown Voltage: 6.4–7.2 V @ 5.0 mA
- ESD Protection Meeting: 16 kV Human Body Model
30 kV Contact = IEC61000-4-2
- Peak Power: 24 W @ 1.0 ms (Unidirectional), per Figure 1
- Peak Power: 150 W @ 20 μ s (Unidirectional), per Figure 2

Mechanical Characteristics

- Void Free, Transfer-Molded, Thermosetting Plastic Case
- Corrosion Resistant Finish, Easily Solderable
- Package Designed for Optimal Automated Board Assembly
- Small Package Size for High Density Applications

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Steady State Power Dissipation Derate above 25°C (Note 1)	P_D	200 1.6	mW mW/°C
Thermal Resistance Junction-to-Ambient	$R_{\theta JA}$	618	°C/W
Operating Junction and Storage Temperature Range	T_J, T_{stg}	- 55 to +150	°C
Peak Power Dissipation @ 1.0 ms (Note 2) @ $T_A = 25^\circ\text{C}$	P_{PK}	20	W
Peak Power Dissipation @ 20 μ s (Note 3) @ $T_A = 25^\circ\text{C}$	P_{PK}	150	W
ESD Discharge MIL STD 883C – Method 3015-6 IEC61000-4-2, Air Discharge IEC61000-4-2, Contact Discharge	V_{PP}	16 30 30	kV

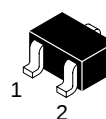
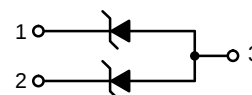
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Mounted on FR-5 Board = 1.0 X 0.75 X 0.062 in.
2. Non-repetitive pulse per Figure 1.
3. Non-repetitive pulse per Figure 2.



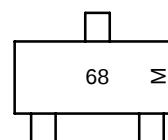
ON Semiconductor®

<http://onsemi.com>



SC-70/SOT-323
CASE 419
STYLE 4

MARKING DIAGRAM



68 = Specific Device Code
M = Date Code

ORDERING INFORMATION

Device	Package	Shipping†
DF3A6.8FUT1	SC-70	3000/Tape & Reel
DF3A6.8FUT1G	SC-70 (Pb-Free)	3000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

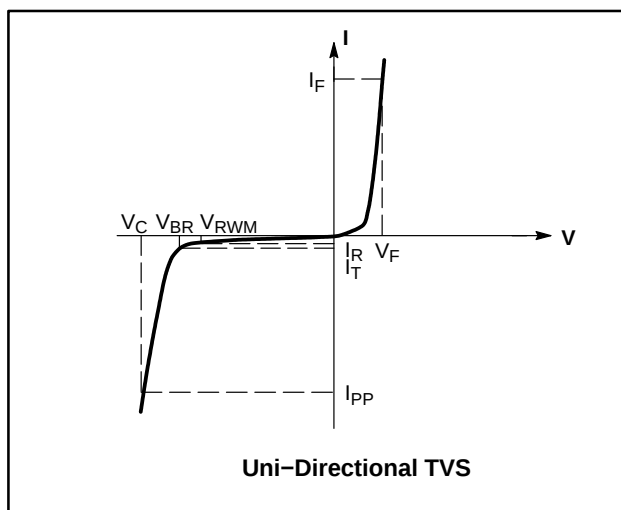
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ELECTRICAL CHARACTERISTICS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

UNIDIRECTIONAL (Circuit tied to Pins 1 and 3 or 2 and 3)

Symbol	Parameter
V_{RWM}	Working Peak Reverse Voltage
I_R	Maximum Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
I_F	Forward Current
V_F	Forward Voltage @ I_F
Z_{ZT}	Maximum Zener Impedance @ I_{ZT}
Z_{ZK}	Maximum Zener Impedance @ I_{ZK}



ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

UNIDIRECTIONAL (Circuit tied to Pins 1 and 3 or 2 and 3)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Forward Voltage	V_F	$I_F = 10\text{ mA}$		0.8	0.9	V
Zener Voltage (Note 4)	V_Z	$I_{ZT} = 5\text{ mA}$	6.4	6.8	7.2	V
Operating Resistance (Note 5)	Z_{ZK}	$I_{ZK} = 0.5\text{ mA}$			200	Ω
	Z_{ZT}	$I_{ZT} = 5\text{ mA}$			50	Ω
Reverse Current	I_{R1}	$V_{RWM} = 5\text{ V}$			0.5	μA
Clamping Voltage	V_C	$I_{PP} = 2.0\text{ A}$ (Figure 1)			9.6	V
		$I_{PP} = 9.37\text{ A}$ (Figure 2)			16	V
ESD Protection						kV
Human Body Model (HBM)					16	
Contact – IEC61000-4-2					30	
Air Discharge					30	

4. V_Z measured at pulse test current I_{ZT} at an ambient temperature of 25°C .

5. Z_{ZT} and Z_{ZK} is measured by dividing the AC voltage drop across the device by the AC current supplied. AC frequency = 1.0 kHz.

TYPICAL CHARACTERISTICS

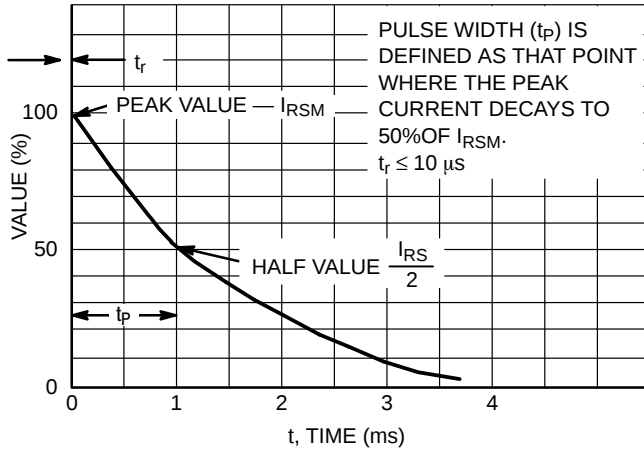


Figure 1. 10 × 1000 μs Pulse Waveform

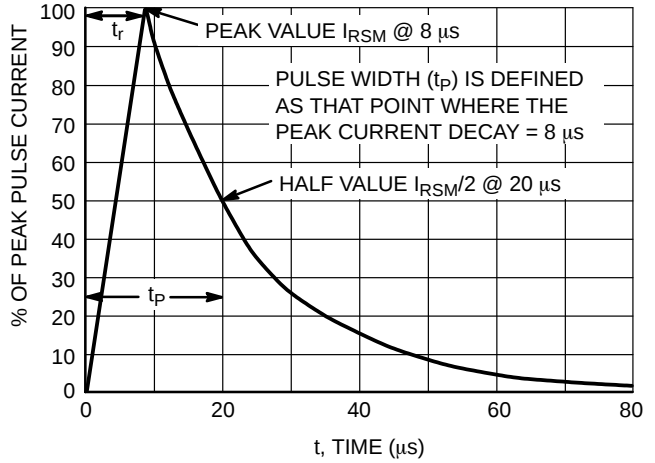


Figure 2. 8 × 20 μs Pulse Waveform

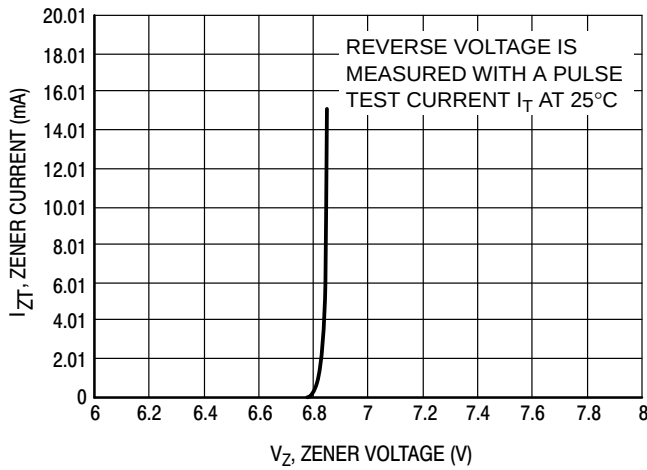


Figure 3. Zener Voltage vs. Zener Current

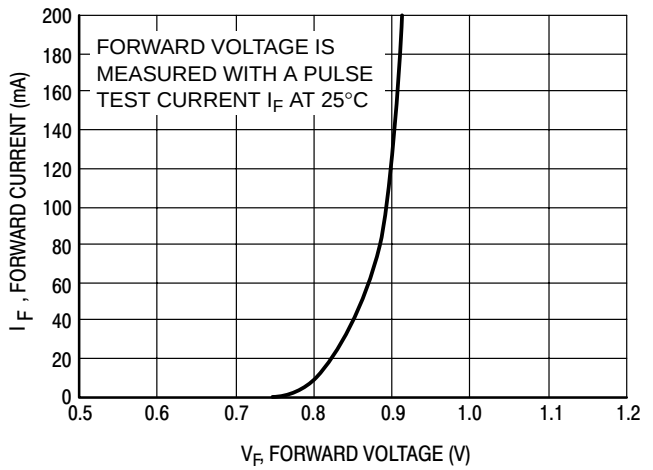


Figure 4. Forward Voltage vs. Forward Current

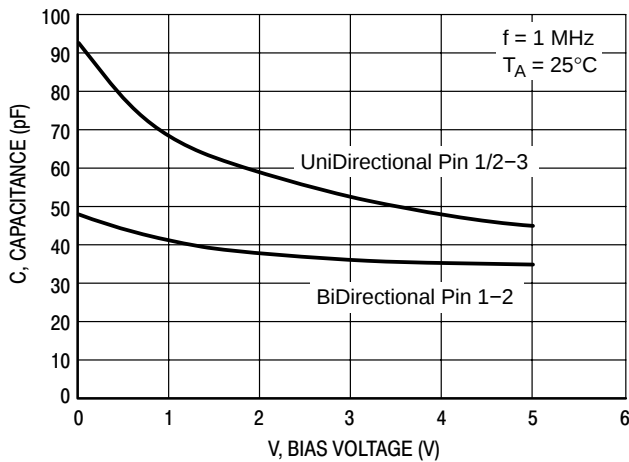


Figure 5. Capacitance vs. Bias Voltage

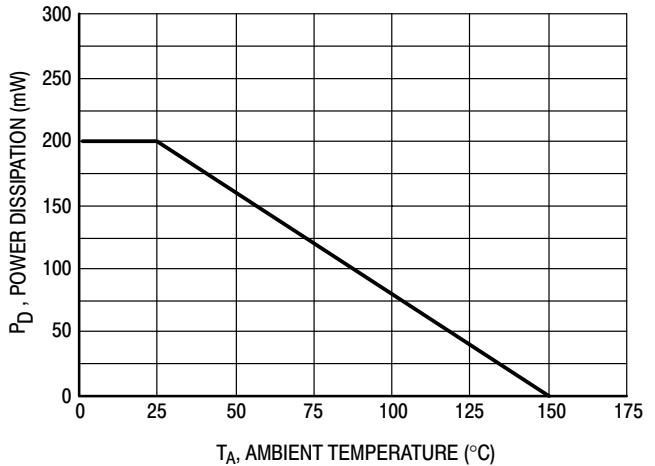
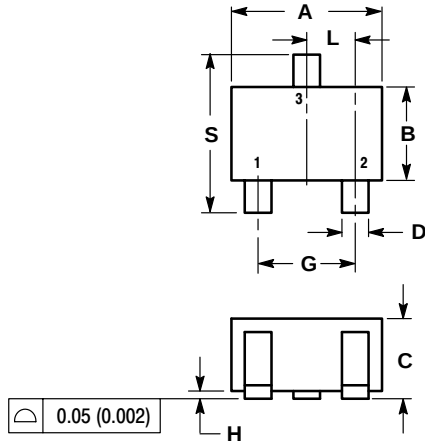


Figure 6. Steady State Power Derating Curve

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PACKAGE DIMENSIONS

SC-70 (SOT-323) CASE 419-04 ISSUE L



NOTES:

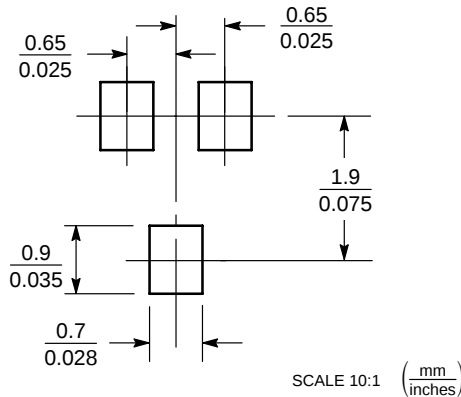
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.032	0.040	0.80	1.00
D	0.012	0.016	0.30	0.40
G	0.047	0.055	1.20	1.40
H	0.000	0.004	0.00	0.10
J	0.004	0.010	0.10	0.25
K	0.017 REF		0.425 REF	
L	0.026 BSC		0.650 BSC	
N	0.028 REF		0.700 REF	
S	0.079	0.095	2.00	2.40

STYLE 4:

- PIN 1: CATHODE
- CATHODE
- ANODE

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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